

SEMICONDUCTOR TECHNICAL DATA

Z5W27V

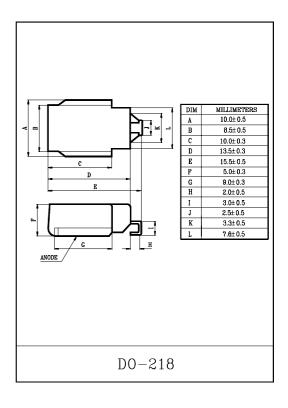
ZENER DIODE SILICON DIFFUSED-JUNCTION TYPE

BEST SUITED FOR OVERVOLTAGE PROTECTION OF ELECTRONIC SYSTEM:

ELECTRONIC SYSTEM FOR USE IN AUTOMOBILES ELECTRONIC SYSTEM FOR COMMERCIAL USE ELECTRONIC SYSTEM FOR INDUSTRIAL USE FOR COMMUNICATIONS, CONTROLS, MEASURING INSTRUMENTS, ETC.

FEATURES

- Excellent clamp voltage characteristics that protect electronic system from any kind of surge.
- High surge power withstanding capabilities that absorb load dump surge.
- Excellent surge responsibility for steep surge absorption.
- Surface mount type is available for easy applications. Zxial lead type is also available.
- \cdot Although the typical zener voltage is V_Z =27V, we can provide the products other than the typical values.
- · Corresponds to taping packages. (500P/Reel)



MAXIMUM RATINGS (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Allowable Power Dissipation (Note 1)	Р	5	W	
Non-Repetitive Peak Reverse Surge Current (See Fig.1 for the exponents.)	$I_{ m RSM}$	62	A	
Junction Temperature	T_{i}	-40~150	${\mathbb C}$	
Storage Temperature Range	$T_{ m stg}$	-40~150	${\mathbb C}$	

Note 1: Lead tip temperature $T_L=25^{\circ}C$.

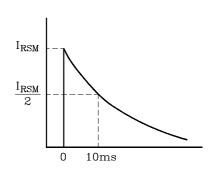


Fig.1

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	ТҮР.	MAX.	UNIT
Zener Voltage	V_Z	I _Z =10mA	24.0	27	30.0	V
Operating Resistance	$r_{ m d}$	I _Z =10mA	-	-	30	Ω
Temperature Coefficient	αт	I _Z =10mA	-	23	36	mV/℃
Forward Voltage	V_{F}	I _F =6A	-	-	1.2	V
Reverse Current	$ m I_R$	V_R =22 V	-	-	10	μΑ

